NSN 5962-01-444-9515

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View Online at https://aerobasegroup.com/nsn/5962-01-444-9515

Body Length:
1.700 inches
Body Width:
Between 0.390 inches and 0.420 inches
Body Height:
0.232 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive and monolithic and low power and static operation
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
85.00 nanoseconds af output megawatts
Memory Device Type:
Ram
Special Features:
Circuit function-dual ce
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
32 printed circuit
Shalf Life:

N/a

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In	18	<i>(</i>)+	МЛО	201	ure:

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Demilitarization:

No

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